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NCP4423, NCP4424, NCP4425
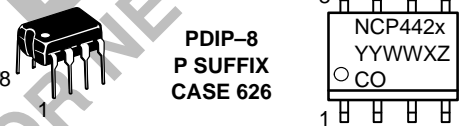
3 A Dual High-Speed MOSFET Drivers

The NCP4423/4424/4425 are MOSFET drivers that are capable of giving reliable service in demanding electrical environments.

Although primarily intended for driving power MOSFETs, these drivers are well–suited for driving other loads (capacitive, resistive, or inductive) which require a low impedance driver capable of high peak currents and fast switching times. Applications such as heavily loaded clock lines, coaxial cables, or piezoelectric transducers can all be driven with the NCP4423/4424/4425. The only known limitation on loading is that the total power dissipated of the driver must be kept within the maximum power dissipation limits of the package.

Features

- High Peak Output Current (3 A)
- Wide Operating Range (4.5 V to 18 V)
- High Capacitive Load Drive Capability (1800 pF in 25 nsec)
- Short Delay Times (< 40 nsec Typ)
- Matched Rise/Fall Times
- Low Supply Current
  With Logic "1" Input (3.5 mA)
  With Logic "0" Input (350 μA)
- Low Output Impedance (3.5 Ω Typ)
- Latch–Up Protected: Will Withstand 1.5 A Reverse Current
- Logic Input Will Withstand Negative Swing Up to 5 V
- ESD Protected (4 kV)

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MARKING DIAGRAM

SO–16
DW SUFFIX
CASE 751G

NCP442x
YYWWXZ

PDIP–8
P SUFFIX
CASE 626

NCP442x
YYWWXZ
CO

x = Device Number (3, 4, or 5)
YY = Year
WW = Work Week
X = Assembly ID Code
Z = Subcontractor ID Code
CO = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
NCP4423DWR2	SO–16	1000 Tape & Reel
NCP4424DWR2	SO–16	1000 Tape & Reel
NCP4425DWR2	SO–16	1000 Tape & Reel
NCP4423P	PDIP–8	50 Units/Rail
NCP4424P	PDIP–8	50 Units/Rail
NCP4425P	PDIP–8	50 Units/Rail

FUNCTIONAL BLOCK DIAGRAM

NCP4423 DUAL INVERTING
NCP4424 DUAL NONINVERTING
NCP4425 ONE INV., ONE NONINV.

EFFECTIVE
INPUT C = 20 pF
(EACH INPUT)
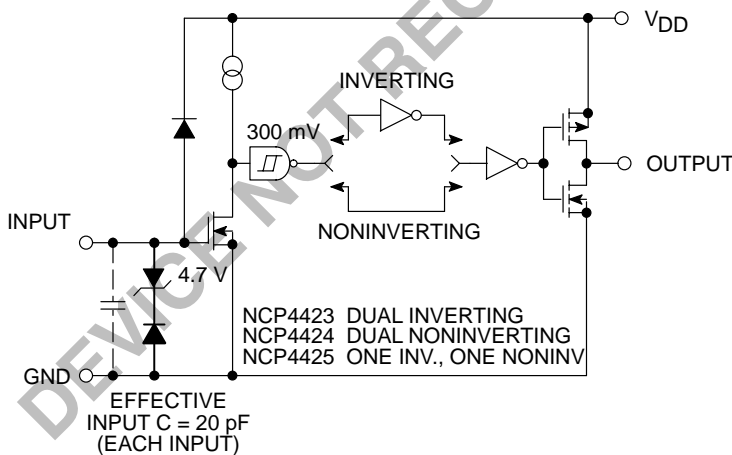
NOTES:
1. NCP4425 has one inverting and one noninverting driver.
2. Ground any unused driver input.

August, 2002 – Rev. 2

NCP4423, NCP4424, NCP4425

PIN CONNECTIONS

16–Pin SO Wide

			4423	**4424**	**4425**
NC	1	16	NC	NC	NC
IN A	2	15	$\overline{\text{OUT A}}$	OUT A	$\overline{\text{OUT A}}$
NC	3	14	$\overline{\text{OUT A}}$	OUT A	$\overline{\text{OUT A}}$
GND	4	13	V_{DD}	V_{DD}	V_{DD}
GND	5	12	V_{DD}	V_{DD}	V_{DD}
NC	6	11	$\overline{\text{OUT B}}$	OUT B	OUT B
IN B	7	10	$\overline{\text{OUT B}}$	OUT B	OUT B
NC	8	9	NC	NC	NC

NCP4423
NCP4424
NCP4425

(Top View)

8–Pin DIP

1		8
2	NCP4423	7
3	NCP4424	6
4	NCP4425	5
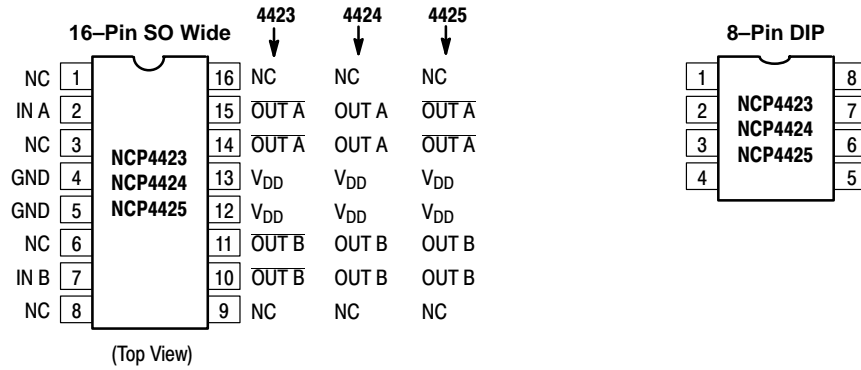
NC = NO CONNECTION
NOTE: Duplicate pins must **both** be connected for proper operation.

ABSOLUTE MAXIMUM RATINGS

Rating	Value	Unit
Supply Voltage	+22	V
Input Voltage, IN A or IN B (V_{DD} + 0.3 V to GND – 5.0 V)	–5	V
Maximum Chip Temperature	+150	°C
Storage Temperature Range, T_{stg}	–65 to +150	°C
Lead Temperature (Soldering, 10 sec)	+300	°C
Package Thermal Resistance SOIC, $R_{\theta JA}$ PDIP, $R_{\theta JA}$ PDIP, $R_{\theta JC}$	155 –125 –45	°C/W
Operating Temperature Range	–40 to +85	°C
Package Power Dissipation ($T_A \leq 70°C$) SOIC PDIP	470 730	mW mc

ELECTRICAL CHARACTERISTICS (T_A = +25°C with 4.5 V $\leq V_{DD} \leq$ 18 V, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Input						
Logic 1 High Input Voltage	V_{OH}	–	2.4	–	–	V
Logic 0 Low Input Voltage	V_{IL}	–	–	–	0.8	V
Input Current	I_{IN}	0 V $\leq V_{IN} \leq V_{DD}$	–1.0	–	1.0	µA
Output						
High Output Voltage	V_{OH}	–	V_{DD} –0.025	–	–	V
Low Output Voltage	V_{OL}	–	–	–	0.025	V
Output Resistance, High	R_{OH}	I_{OUT} = 10 mA, V_{DD} = 18 V	–	2.8	5.0	Ω
Output Resistance, Low	R_{OL}	I_{OUT} = 10 mA, V_{DD} = 18 V	–	3.5	5.0	Ω
Peak Output Current	I_{PK}	–	–	3.0	–	A
Latch–Up Protection Withstand Reverse Current	I_{REV}	Duty Cycle $\leq$ 2% t $\leq$ 300 µs	1.5	–	–	A
Switching Time (Note 1)						
Rise Time	t_R	Figure 1, C_L = 1800 pF	–	23	35	nsec
Fall Time	t_F	Figure 1, C_L = 1800 pF	–	25	35	nsec
Delay Time 1	t_{D1}	Figure 1, C_L = 1800 pF	–	33	75	nsec
Delay Time 2	t_{D2}	Figure 1, C_L = 1800 pF	–	38	75	nsec
Power Supply						
Power Supply Current	I_S	V_{IN} = 3.0 V (Both Inputs) V_{IN} = 0 V (Both Inputs)	– –	1.5 0.15	2.5 0.25	mA

1. Switching times guaranteed by design.

ELECTRICAL CHARACTERISTICS (Over operating temperature range with 4.5 V $\leq$ V$_{DD}$ $\leq$ 18 V, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Input						
Logic 1 High Input Voltage	V$_{IH}$	–	2.4	–	–	V
Logic 0 Low Input Voltage	V$_{IL}$	–	–	–	0.8	V
Input Current	I$_{IN}$	0 V $\leq$ V$_{IN}$ $\leq$ V$_{DD}$	–10	–	10	μA
Output						
High Output Voltage	V$_{OH}$	–	V$_{DD}$ –0.025	–	–	V
Low Output Voltage	V$_{OL}$	–	–	–	0.025	V
Output Resistance, High	R$_O$	I$_{OUT}$ = 10 mA, V$_{DD}$ = 18 V	–	3.7	8.0	Ω
Output Resistance, Low	R$_O$	I$_{OUT}$ = 10 mA, V$_{DD}$ = 18 V	–	4.3	8.0	Ω
Peak Output Current	I$_{PK}$	–	–	3.0	–	A
Latch–Up Protection Withstand Reverse Current	I$_{REV}$	Duty Cycle $\leq$ 2% t $\leq$ 300 μsec	1.5	–	–	A
Switching Time (Note 1)						
Rise Time	t$_R$	Figure 1, C$_L$ = 1800 pF	–	28	60	nsec
Fall Time	t$_F$	Figure 1, C$_L$ = 1800 pF	–	32	60	nsec
Delay Time 1	t$_{D1}$	Figure 1, C$_L$ = 1800 pF	–	32	100	nsec
Delay Time 2	t$_{D2}$	Figure 1, C$_L$ = 1800 pF	–	38	100	nsec
Power Supply						
Power Supply Current	I$_S$	V$_{IN}$ = 3.0 V (Both Inputs) V$_{IN}$ = 0 V (Both Inputs)	– –	2.0 0.2	3.5 0.3	mA

1. Switching times guaranteed by design.
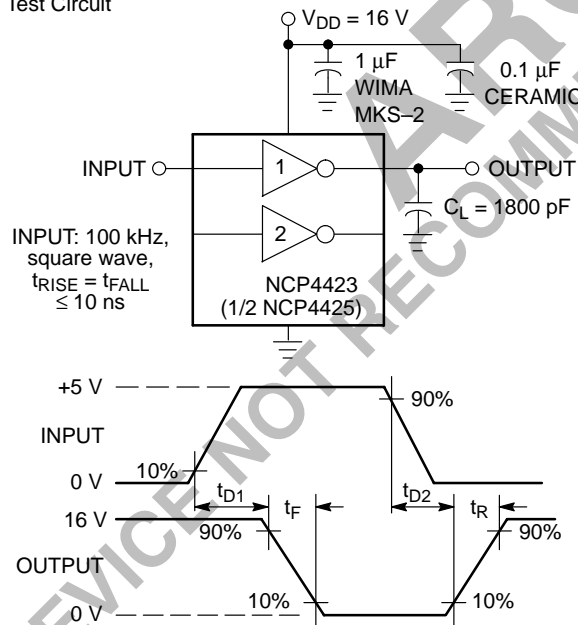
Figure 1. Inverting Driver Switching Time
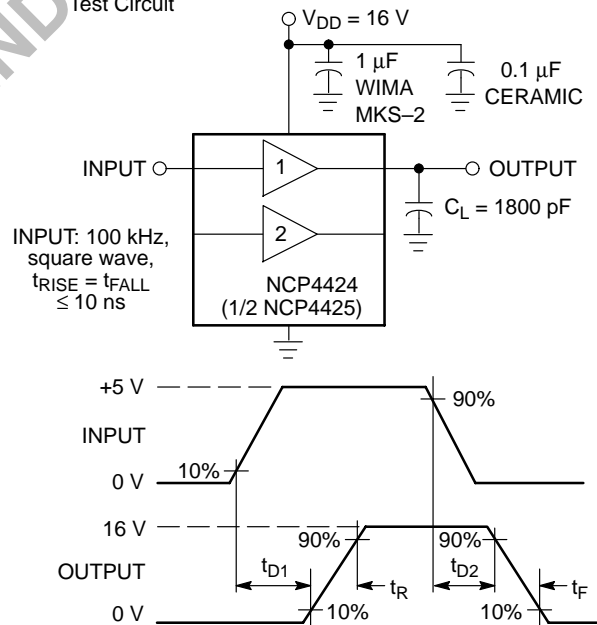
Figure 2. Noninverting Driver Switching Time

TYPICAL ELECTRICAL CHARACTERISTICS
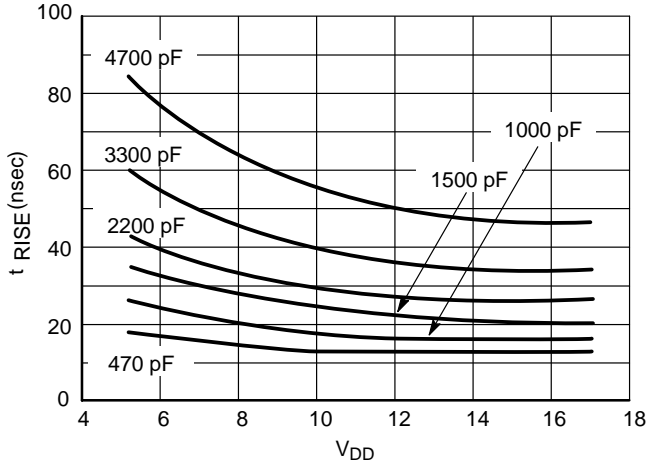
Figure 3. Rise Time vs. Supply Voltage
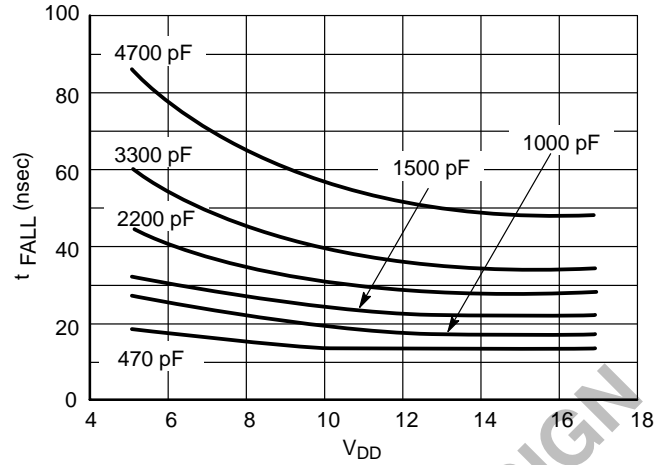
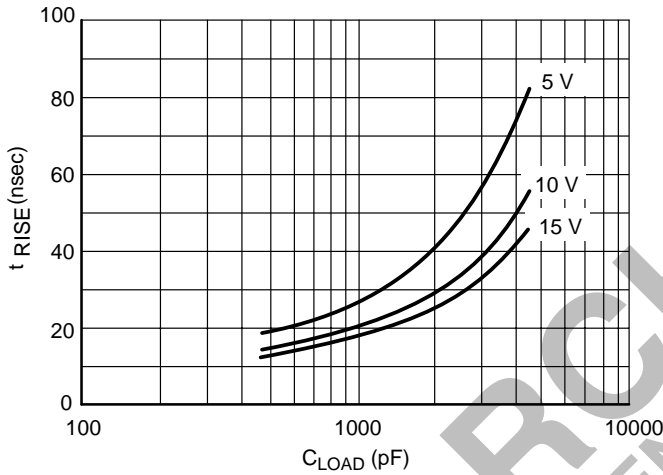**Figure 4. Fall Time vs. Supply Voltage**

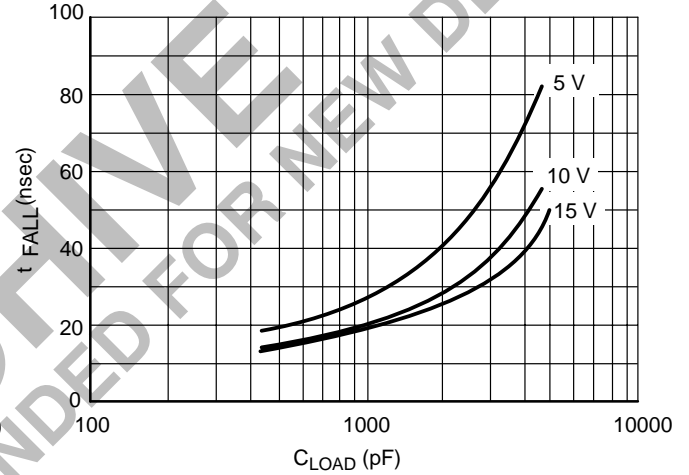**Figure 5. Rise Time vs. Capacitive Load**

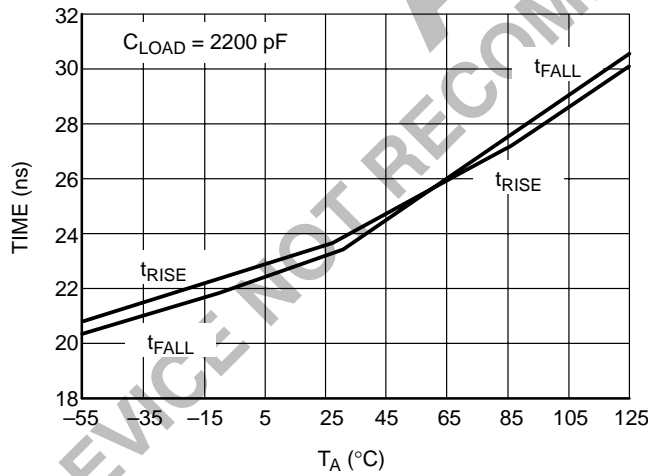**Figure 6. Fall Time vs. Capacitive Load**

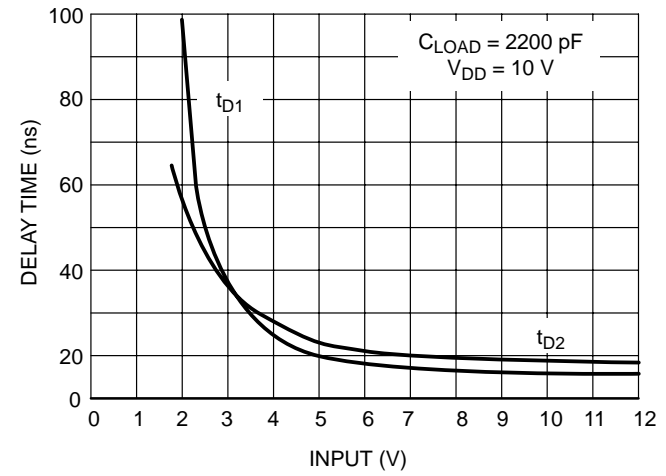**Figure 7. Rise and Fall Times vs. Temperature**

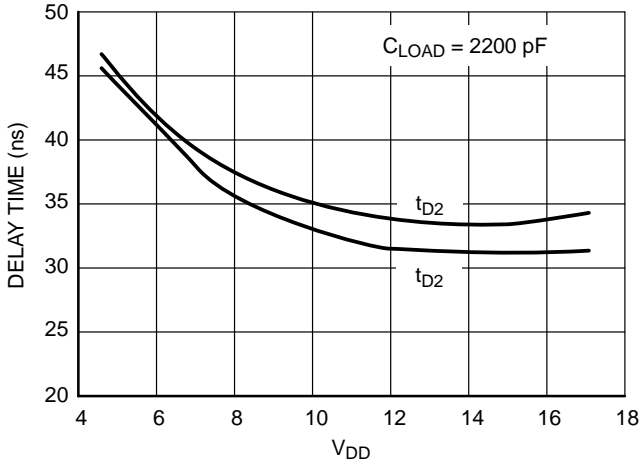**Figure 8. Propagation Delay vs. Input Amplitude**

TYPICAL ELECTRICAL CHARACTERISTICS
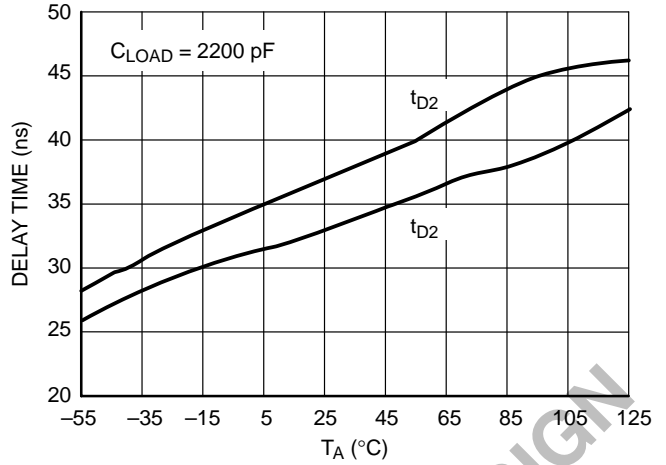
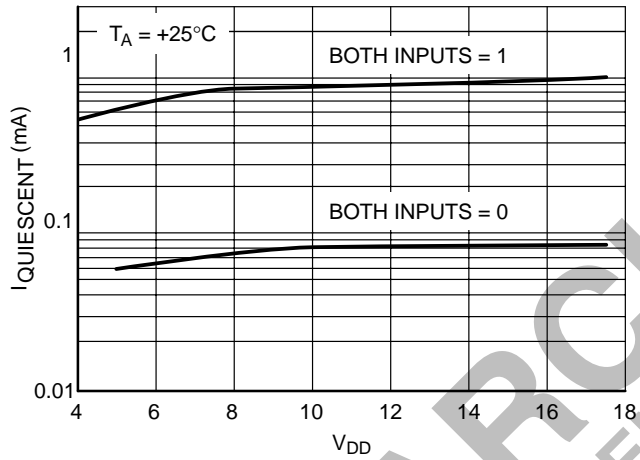**Figure 9. Propagation Delay Time vs. Supply Voltage**

Figure 10. Delay Time vs. Temperature

Figure 11. Quiescent Current vs. Supply Voltage
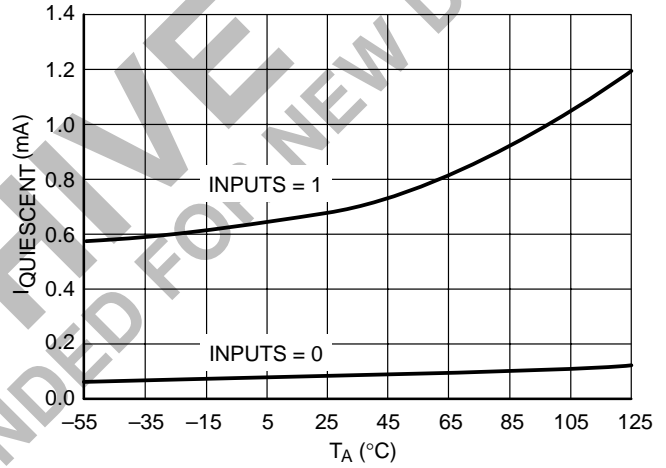
Figure 12. Quiescent Current vs. Temperature
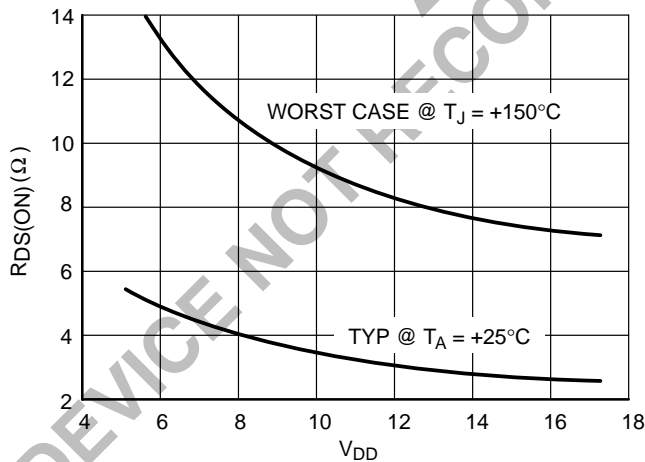
Figure 13. Output Resistance (Output High) vs. Supply Voltage
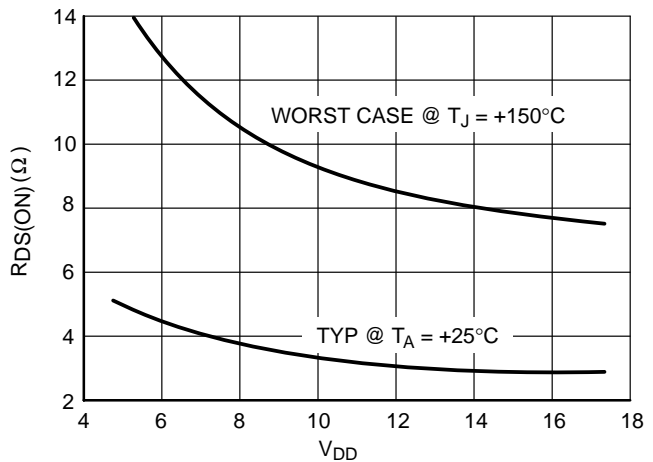
Figure 14. Output Resistance (Output Low) vs. Supply Voltage

TYPICAL ELECTRICAL CHARACTERISTICS
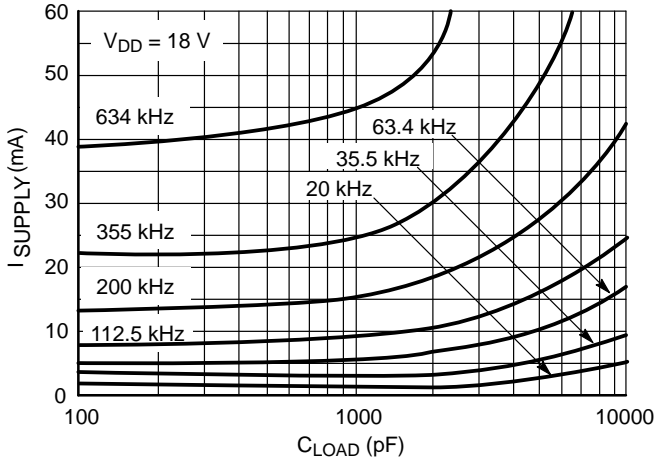
Figure 15. Supply Current vs. Capacitive Load
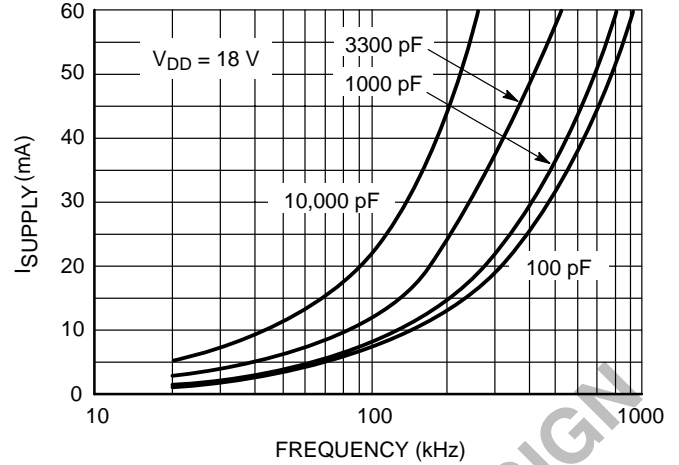
Figure 16. Supply Current vs. Frequency
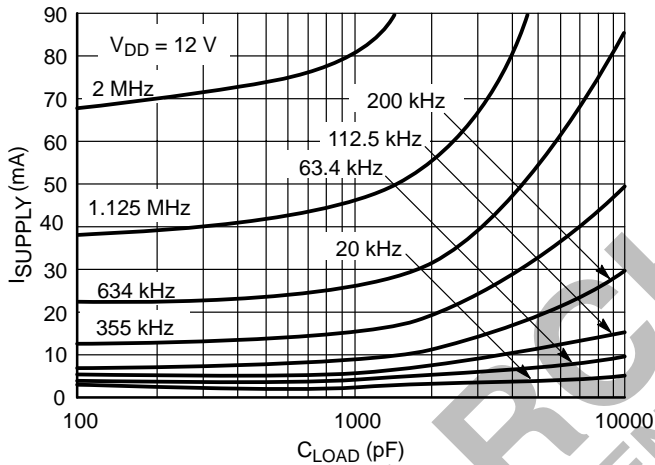
Figure 17. Supply Current vs. Capacitive Load
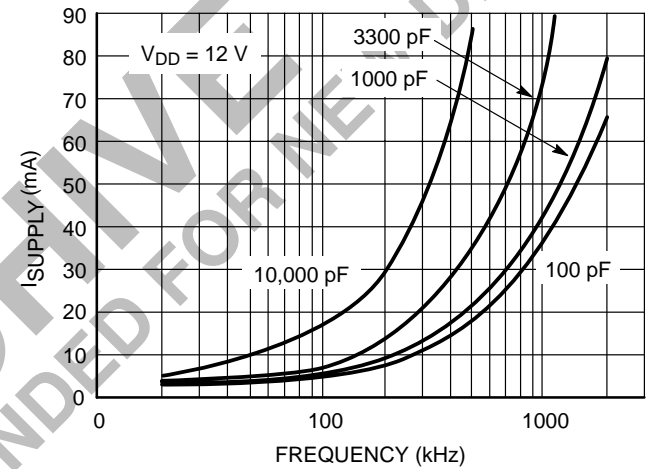
Figure 18. Supply Current vs. Frequency
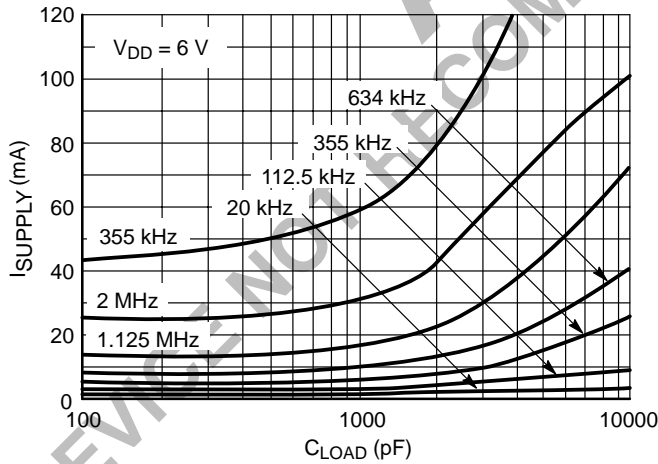
Figure 19. Supply Current vs. Capacitive Load
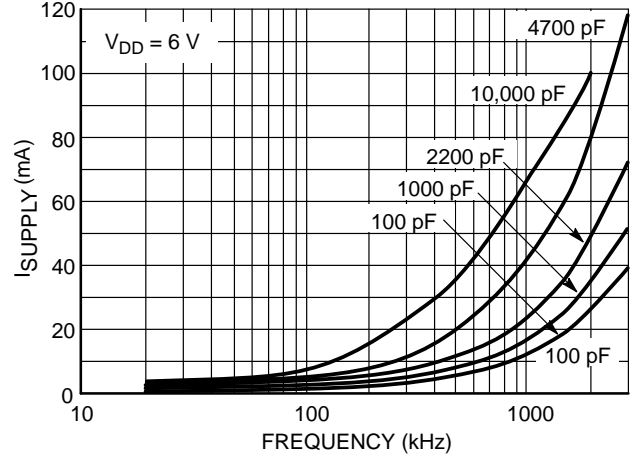
Figure 20. Supply Current vs. Frequency
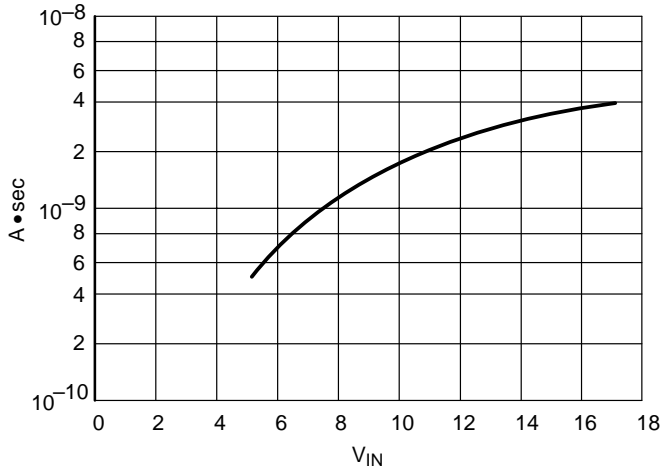
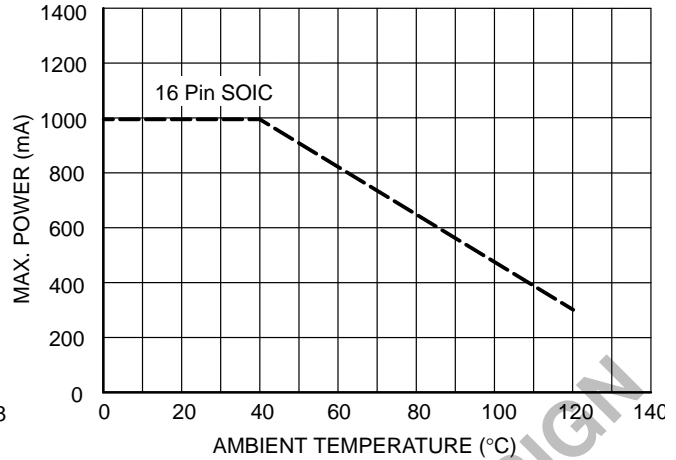## TYPICAL ELECTRICAL CHARACTERISTICS

Figure 21. NCP4423 Crossover Energy

Figure 22. Thermal Derating Curves

NOTE: The values on this graph represent the loss seen by both drivers in a package during one complete cycle. For a single driver, divide the stated values by 2. For a single transition of a single driver, divide the stated value by 4.

Static–sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under Absolute Maximum Ratings (See page 2) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability.

PACKAGE DIMENSIONS

PDIP–8
P SUFFIX
CASE 626–05
ISSUE K
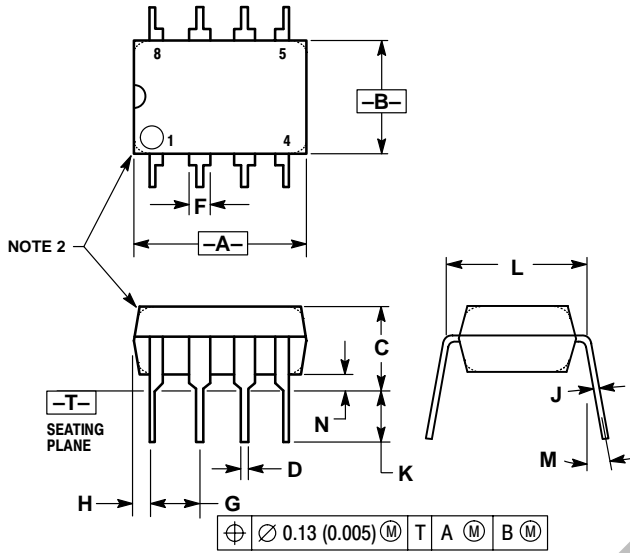
NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	—	10°
N	0.76	1.01	0.030	0.040

SO–16
DW SUFFIX
CASE 751G–03
ISSUE B
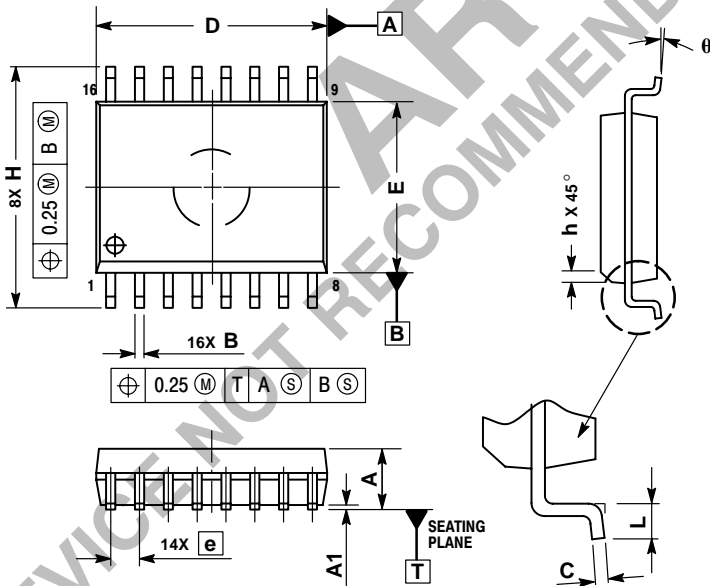
NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	10.15	10.45
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

<u>Notes</u>

Notes

NCP4423, NCP4424, NCP4425

PUBLICATION ORDERING INFORMATION

NCP4423/D